National Semiconductor

CD4013BM/CD4013BC Dual D Flip-Flop

General Description

The CD4013B dual D flip-flop is a monolithic complementary MOS (CMOS) integrated circuit constructed with N- and P-channel enhancement mode transistors. Each flip-flop has independent data, set, reset, and clock inputs and "Q" and "Q̄" outputs. These devices can be used for shift register applications, and by connecting "Q̄" output to the data input, for counter and toggle applications. The logic level present at the "D" input is transferred to the Q output during the positive-going transition of the clock pulse. Setting or resetting is independent of the clock and is accomplished by a high level on the set or reset line respectively.
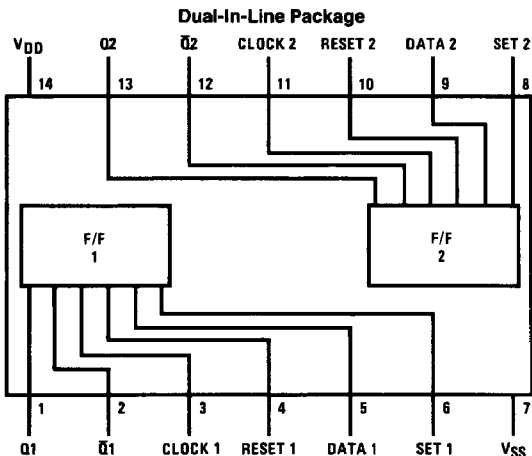
Features

- Wide supply voltage range   3.0V to 15V
- High noise immunity   0.45 V_{DD} (typ.)
- Low power TTL
  compatibility   fan out of 2 driving 74L
  or 1 driving 74LS

Applications

- Automotive
- Data terminals
- Instrumentation
- Medical electronics
- Alarm system
- Industrial electronics
- Remote metering
- Computers

Connection Diagram

Dual-In-Line Package

Top View

Order Number CD4013B*

Please see Section 8, Appendix D
for availability of various package types.

TL/F/5946–1

Truth Table

CL†	D	R	S	Q	Q̄
⤴	0	0	0	0	1
⤴	1	0	0	1	0
⤵	x	0	0	Q	Q̄
x	x	1	0	0	1
x	x	0	1	1	0
x	x	1	1	1	1

No change
† = Level change
x = Don't care case

Absolute Maximum Ratings (Notes 1 & 2)

If Military/Aerospace specified devices are required, contact the National Semiconductor Sales Office/Distributors for availability and specifications.

DC Supply Voltage (V_{DD}) $-0.5\ V_{DC}$ to $+18\ V_{DC}$

Input Voltage (V_{IN}) $-0.5\ V_{DC}$ to $V_{DD} + 0.5\ V_{DC}$

Storage Temp. Range (T_S) $-65°C$ to $+150°C$

Power Dissipation (P_D)
   Dual-In-Line   700 mW
   Small Outline   500 mW

Lead Temperature (T_L)
(Soldering, 10 seconds)   260°C

Recommended Operating Conditions (Note 2)

DC Supply Voltage (V_{DD}) $+3\ V_{DC}$ to $+15\ V_{DC}$

Input Voltage (V_{IN}) $0\ V_{DC}$ to $V_{DD}\ V_{DC}$

Operating Temperature Range (T_A)
   CD4013BM $-55°C$ to $+125°C$
   CD4013BC $-40°C$ to $+85°C$

DC Electrical Characteristics CD4013BM (Note 2)

Symbol	Parameter	Conditions	−55°C Min	−55°C Max	+25°C Min	+25°C Typ	+25°C Max	+125°C Min	+125°C Max	Units
I_{DD}	Quiescent Device Current	$V_{DD} = 5V$, $V_{IN} = V_{DD}$ or V_{SS}		1.0			1.0		30	μA
		$V_{DD} = 10V$, $V_{IN} = V_{DD}$ or V_{SS}		2.0			2.0		60	μA
		$V_{DD} = 15V$, $V_{IN} = V_{DD}$ or V_{SS}		4.0			4.0		120	μA
V_{OL}	Low Level Output Voltage	$|I_O| < 1.0\ μA$								
		$V_{DD} = 5V$		0.05			0.05		0.05	V
		$V_{DD} = 10V$		0.05			0.05		0.05	V
		$V_{DD} = 15V$		0.05			0.05		0.05	V
V_{OH}	High Level Output Voltage	$|I_O| < 1.0\ μA$								
		$V_{DD} = 5V$	4.95		4.95			4.95		V
		$V_{DD} = 10V$	9.95		9.95			9.95		V
		$V_{DD} = 15V$	14.95		14.95			14.95		V
V_{IL}	Low Level Input Voltage	$|I_O| < 1.0\ μA$								
		$V_{DD} = 5V$, $V_O = 0.5V$ or $4.5V$		1.5			1.5		1.5	V
		$V_{DD} = 10V$, $V_O = 1.0V$ or $9.0V$		3.0			3.0		3.0	V
		$V_{DD} = 15V$, $V_O = 1.5V$ or $13.5V$		4.0			4.0		4.0	V
V_{IH}	High Level Input Voltage	$|I_O| < 1.0\ μA$								
		$V_{DD} = 5V$, $V_O = 0.5V$ or $4.5V$	3.5		3.5			3.5		V
		$V_{DD} = 10V$, $V_O = 1.0V$ or $9.0V$	7.0		7.0			7.0		V
		$V_{DD} = 15V$, $V_O = 1.5V$ or $13.5V$	11.0		11.0			11.0		V
I_{OL}	Low Level Output Current (Note 3)	$V_{DD} = 5V$, $V_O = 0.4V$	0.64		0.51	0.88		0.36		mA
		$V_{DD} = 10V$, $V_O = 0.5V$	1.6		1.3	2.25		0.9		mA
		$V_{DD} = 15V$, $V_O = 1.5V$	4.2		3.4	8.8		2.4		mA
I_{OH}	High Level Output Current (Note 3)	$V_{DD} = 5V$, $V_O = 4.6V$	−0.64		−0.51	−0.88		−0.36		mA
		$V_{DD} = 10V$, $V_O = 9.5V$	−1.6		−1.3	−2.25		−0.9		mA
		$V_{DD} = 15V$, $V_O = 13.5V$	−4.2		−3.4	−8.8		−2.4		mA
I_{IN}	Input Current	$V_{DD} = 15V$, $V_{IN} = 0V$		−0.1	-10^{-5}	−0.1			−1.0	μA
		$V_{DD} = 15V$, $V_{IN} = 15V$		0.1	10^{-5}	0.1			1.0	μA

DC Electrical Characteristics CD4013BC (Note 2)

Symbol	Parameter	Conditions	−40°C Min	−40°C Max	+25°C Min	+25°C Typ	+25°C Max	+85°C Min	+85°C Max	Units
I_{DD}	Quiescent Device Current	$V_{DD} = 5V$, $V_{IN} = V_{DD}$ or V_{SS}		4.0			4.0		30	μA
		$V_{DD} = 10V$, $V_{IN} = V_{DD}$ or V_{SS}		8.0			8.0		60	μA
		$V_{DD} = 15V$, $V_{IN} = V_{DD}$ or V_{SS}		16.0			16.0		120	μA
V_{OL}	Low Level Output Voltage	$|I_O| < 1.0\ μA$								
		$V_{DD} = 5V$		0.05			0.05		0.05	V
		$V_{DD} = 10V$		0.05			0.05		0.05	V
		$V_{DD} = 15V$		0.05			0.05		0.05	V
V_{OH}	High Level Output Voltage	$|I_O| < 1.0\ μA$								
		$V_{DD} = 5V$	4.95		4.95			4.95		V
		$V_{DD} = 10V$	9.95		9.95			9.95		V
		$V_{DD} = 15V$	14.95		14.95			14.95		V
V_{IL}	Low Level Input Voltage	$|I_O| < 1.0\ μA$								
		$V_{DD} = 5V$, $V_O = 0.5V$ or $4.5V$		1.5			1.5		1.5	V
		$V_{DD} = 10V$, $V_O = 1.0V$ or $9.0V$		3.0			3.0		3.0	V
		$V_{DD} = 15V$, $V_O = 1.5V$ or $13.5V$		4.0			4.0		4.0	V

DC Electrical Characteristics CD4013BC (Note 2) (Continued)

Symbol	Parameter	Conditions	−40°C Min	−40°C Max	+25°C Min	+25°C Typ	+25°C Max	+85°C Min	+85°C Max	Units
V_{IH}	High Level Input Voltage	$|I_O| < 1.0\ \mu A$ $V_{DD} = 5V$, $V_O = 0.5V$ or 4.5V	3.5		3.5			3.5		V
		$V_{DD} = 10V$, $V_O = 1.0V$ or 9.0V	7.0		7.0			7.0		V
		$V_{DD} = 15V$, $V_O = 1.5V$ or 13.5V	11.0		11.0			11.0		V
I_{OL}	Low Level Output Current (Note 3)	$V_{DD} = 5V$, $V_O = 0.4V$	0.52		0.44	0.88		0.36		mA
		$V_{DD} = 10V$, $V_O = 0.5V$	1.3		1.1	2.25		0.9		mA
		$V_{DD} = 15V$, $V_O = 1.5V$	3.6		3.0	8.8		2.4		mA
I_{OH}	High Level Output Current (Note 3)	$V_{DD} = 5V$, $V_O = 4.6V$	−0.52		−0.44	−0.88		−0.36		mA
		$V_{DD} = 10V$, $V_O = 9.5V$	−1.3		−1.1	−2.25		−0.9		mA
		$V_{DD} = 15V$, $V_O = 13.5V$	−3.6		−3.0	−8.8		−2.4		mA
I_{IN}	Input Current	$V_{DD} = 15V$, $V_{IN} = 0V$		−0.3		-10^{-5}	−0.3		−1.0	μA
		$V_{DD} = 15V$, $V_{IN} = 15V$		0.3		10^{-5}	0.3		1.0	μA

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed, they are not meant to imply that the devices should be operated at these limits. The tables of "Recommended Operating Conditions" and "Electrical Characteristics" provide conditions for actual device operation.
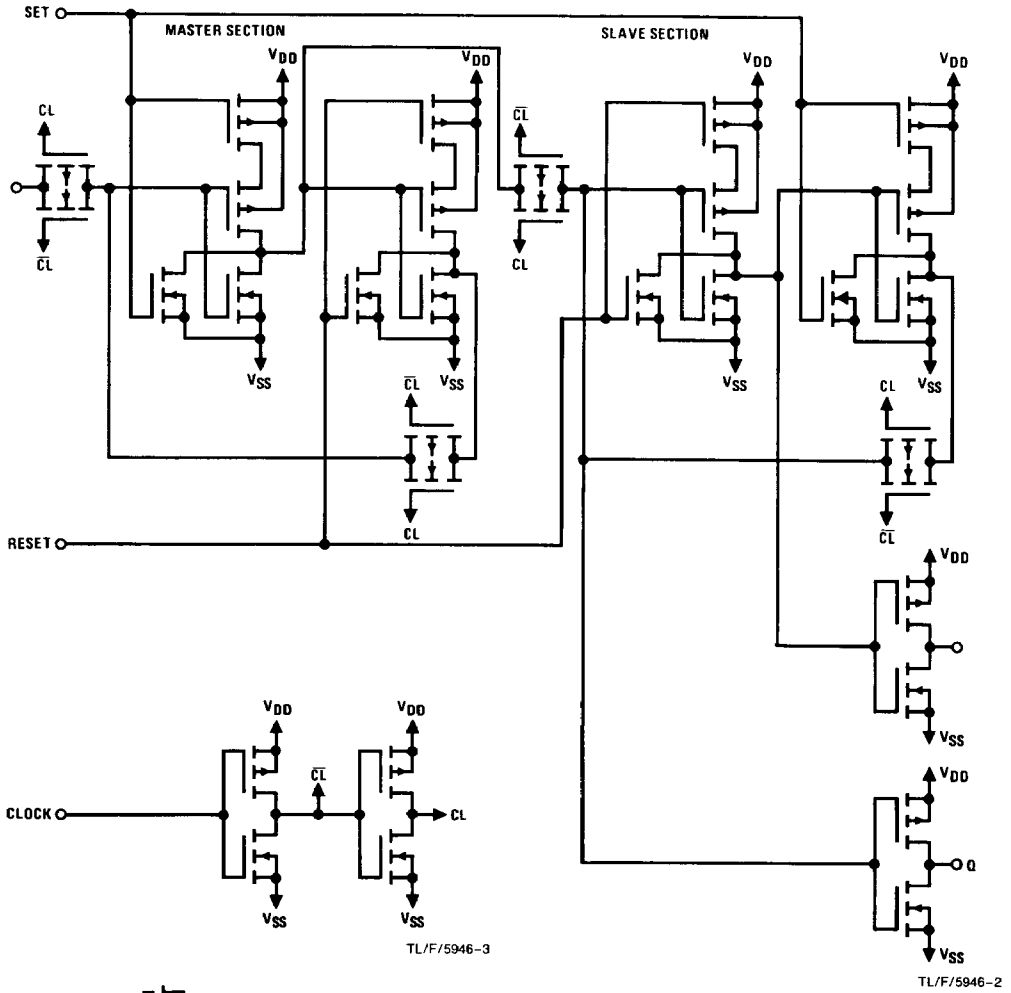
Note 2: $V_{SS} = 0V$ unless otherwise specified.

Note 3: I_{OH} and I_{OL} are measured one output at a time.

AC Electrical Characteristics* $T_A = 25°C$, $C_L = 50$ pF, $R_L = 200k$, unless otherwise noted

Symbol	Parameter	Conditions	Min	Typ	Max	Units
CLOCK OPERATION						
t_{PHL}, t_{PLH}	Propagation Delay Time	$V_{DD} = 5V$		200	350	ns
		$V_{DD} = 10V$		80	160	ns
		$V_{DD} = 15V$		65	120	ns
t_{THL}, t_{TLH}	Transition Time	$V_{DD} = 5V$		100	200	ns
		$V_{DD} = 10V$		50	100	ns
		$V_{DD} = 15V$		40	80	ns
t_{WL}, t_{WH}	Minimum Clock Pulse Width	$V_{DD} = 5V$		100	200	ns
		$V_{DD} = 10V$		40	80	ns
		$V_{DD} = 15V$		32	65	ns
t_{RCL}, t_{FCL}	Maximum Clock Rise and Fall Time	$V_{DD} = 5V$			15	μs
		$V_{DD} = 10V$			10	μs
		$V_{DD} = 15V$			5	μs
t_{SU}	Minimum Set-Up Time	$V_{DD} = 5V$		20	40	ns
		$V_{DD} = 10V$		15	30	ns
		$V_{DD} = 15V$		12	25	ns
f_{CL}	Maximum Clock Frequency	$V_{DD} = 5V$	2.5	5		MHz
		$V_{DD} = 10V$	6.2	12.5		MHz
		$V_{DD} = 15V$	7.6	15.5		MHz
SET AND RESET OPERATION						
$t_{PHL(R)}$, $t_{PLH(S)}$	Propagation Delay Time	$V_{DD} = 5V$		150	300	ns
		$V_{DD} = 10V$		65	130	ns
		$V_{DD} = 15V$		45	90	ns
$t_{WH(R)}$, $t_{WH(S)}$	Minimum Set and Reset Pulse Width	$V_{DD} = 5V$		90	180	ns
		$V_{DD} = 10V$		40	80	ns
		$V_{DD} = 15V$		25	50	ns
C_{IN}	Average Input Capacitance	Any Input		5	7.5	pF

*AC Parameters are guaranteed by DC correlated testing.
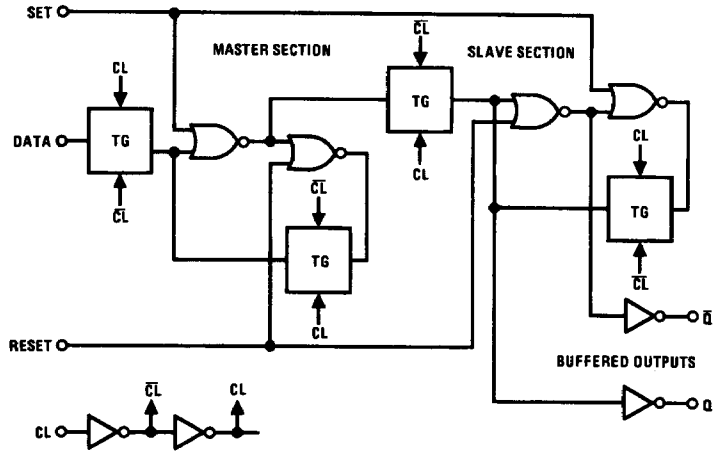
Schematic Diagram

SET

MASTER SECTION

SLAVE SECTION

CL

V_{DD}

V_{DD}

$\overline{CL}$

V_{DD}

V_{DD}

$\overline{CL}$

CL

V_{SS}

$\overline{CL}$ V_{SS}

V_{SS}

CL V_{SS}

$\overline{CL}$

CL

RESET

$\overline{CL}$

V_{DD}

V_{SS}

V_{DD}

V_{DD}

V_{DD}

$\overline{CL}$

V_{DD}

Q

CLOCK

CL

V_{SS}

V_{SS}

V_{SS}

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TL/F/5946–2

ALL P-SUBSTRATES ( ) CONNECTED TO V_{DD}

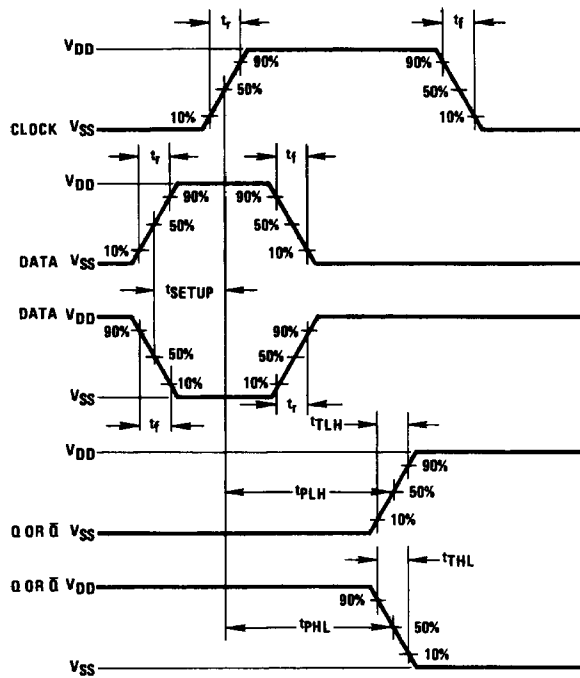ALL N-SUBSTRATES ( ) CONNECTED TO V_{SS}

TL/F/5946–4

5

Logic Diagram

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Switching Time Waveforms

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